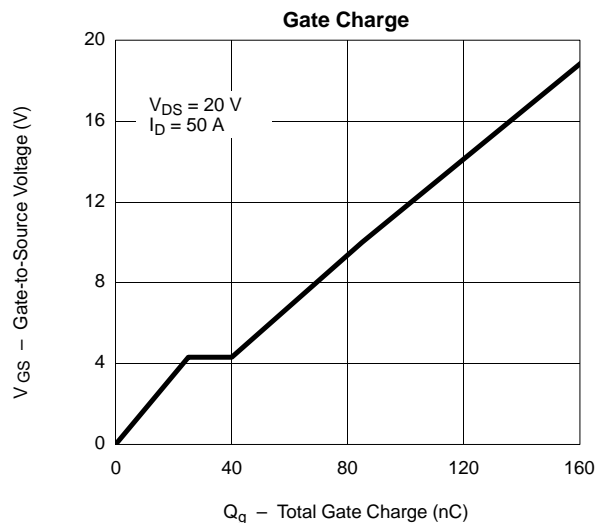
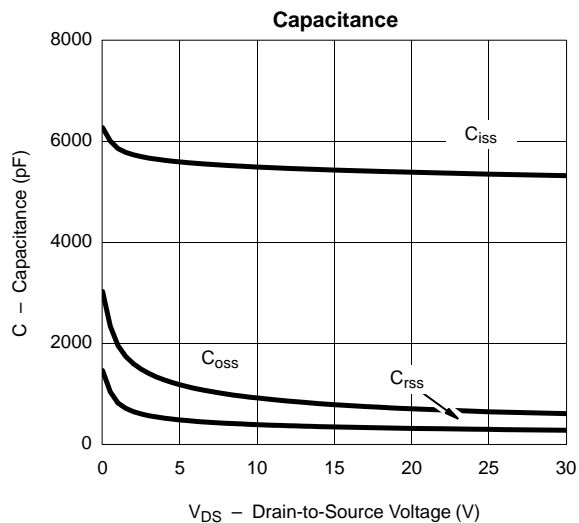
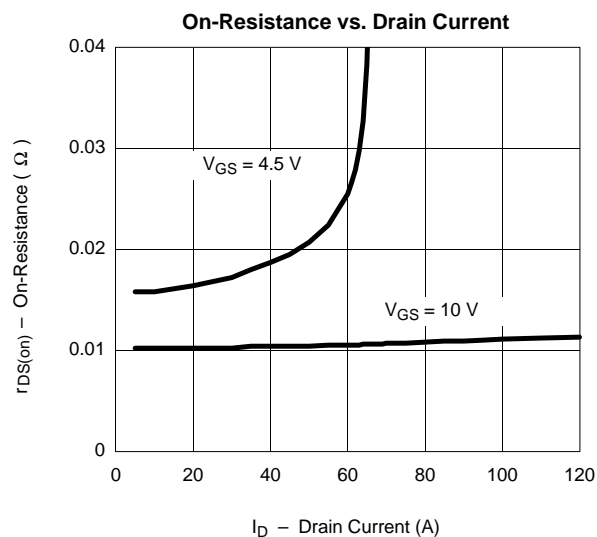
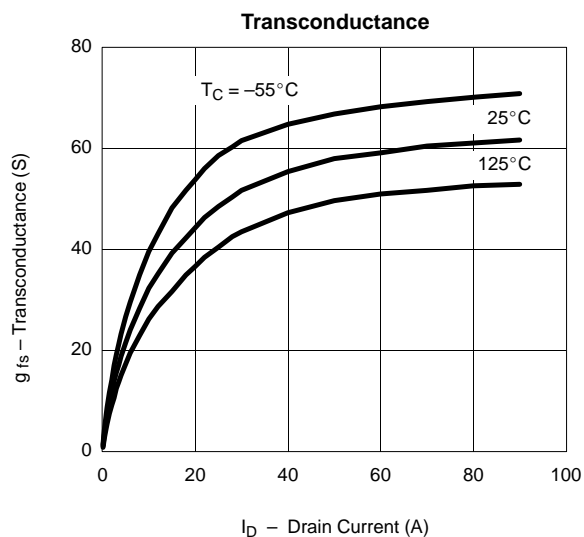
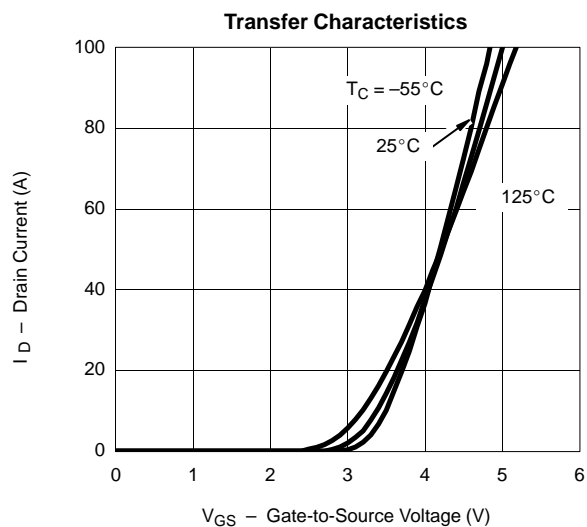
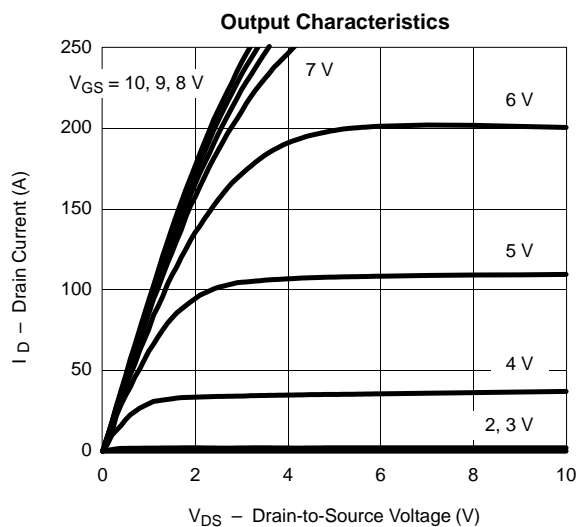


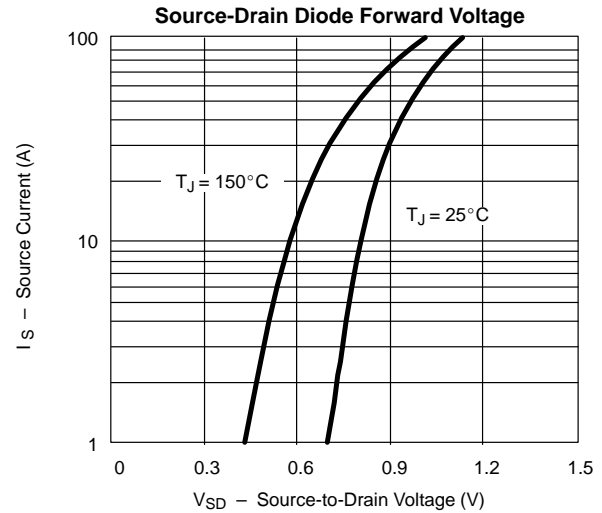
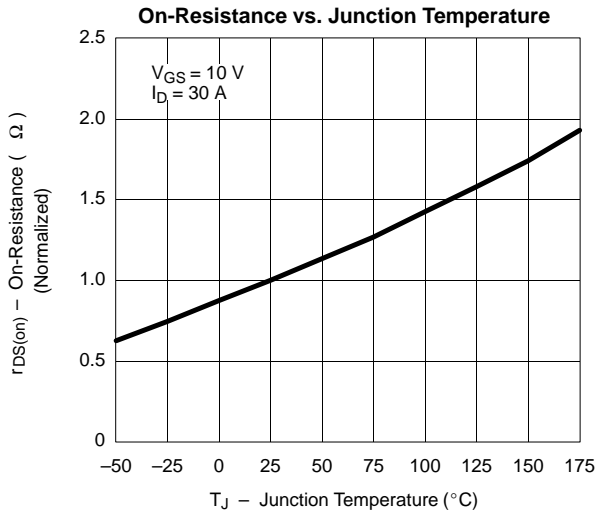
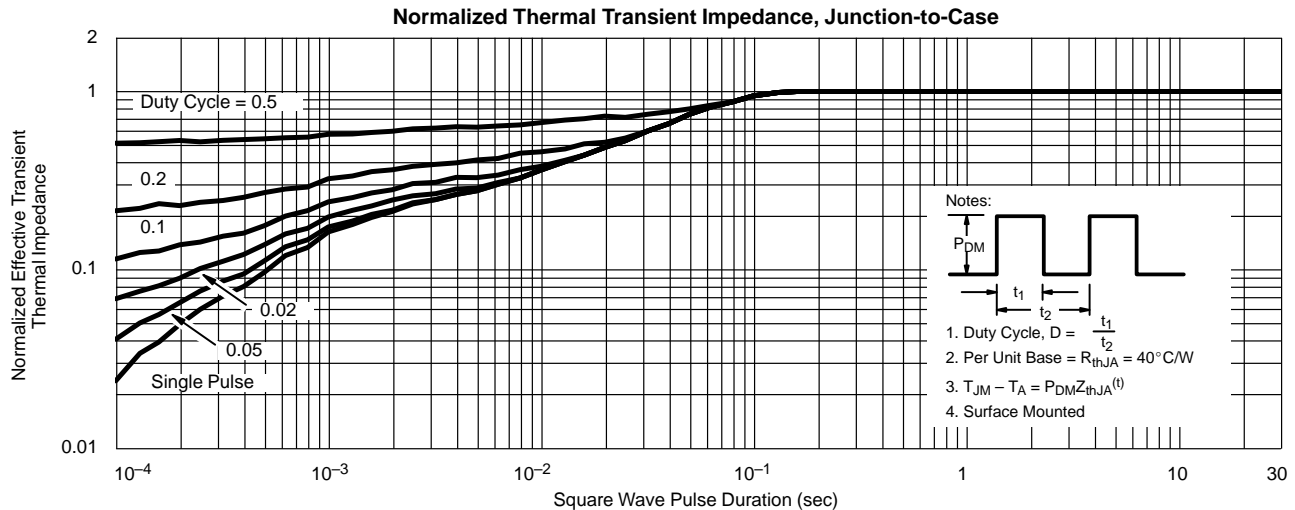
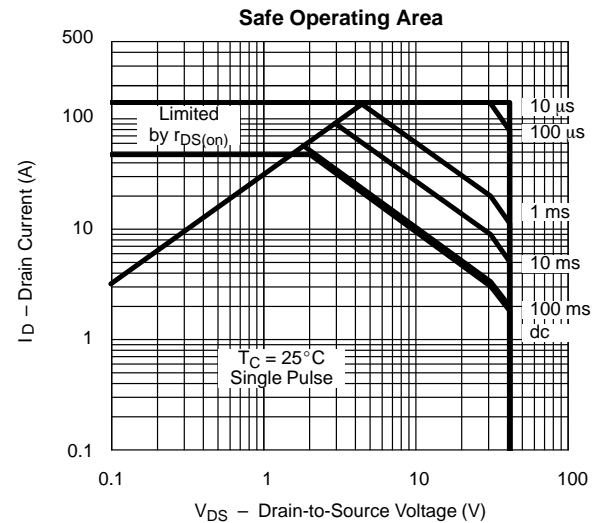
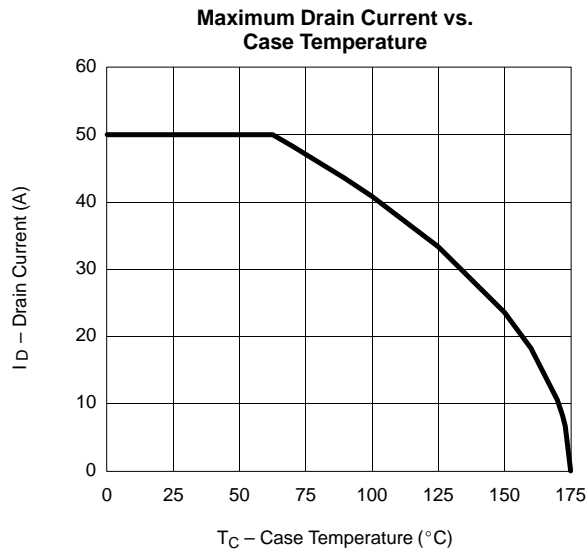
**SPECIFICATIONS (T_J = 25 °C UNLESS OTHERWISE NOTED)**

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0 V, I _D = −250 μA	−40			V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = −250 μA	−1.0			
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 20 V			± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = −40 V, V _{GS} = 0 V			−1	μA
		V _{DS} = −40 V, V _{GS} = 0 V, T _J = 125 °C			−50	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = −5 V, V _{GS} = −10 V	−120			A
Drain-Source On-State Resistance ^a	r _{DS(on)}	V _{GS} = −10 V, I _D = −30 A		0.012	0.015	Ω
		V _{GS} = −10 V, I _D = −30 A, T _J = 125 °C			0.024	
		V _{GS} = −4.5 V, I _D = −20 A		0.018	0.023	
Forward Transconductance ^a	g _{fs}	V _{DS} = −15 V, I _D = −30 A	20			S
Dynamic ^b						
Input Capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = −25 V, f = 1 MHz		5400		pF
Output Capacitance	C _{oss}			640		
Reverse Transfer Capacitance	C _{rss}			300		
Total Gate Charge ^c	Q _g	V _{DS} = −20 V, V _{GS} = −10 V, I _D = −50 A		85	130	nC
Gate-Source Charge ^c	Q _{gs}			25		
Gate-Drain Charge ^c	Q _{gd}			15		
Turn-On Delay Time ^c	t _{d(on)}	V _{DD} = −20 V, R _L = 0.4 Ω I _D ≅ −50 A, V _{GEN} = −10 V, R _G = 2.5 Ω		15	25	ns
Rise Time ^c	t _r			380	580	
Turn-Off Delay Time ^c	t _{d(off)}			75	115	
Fall Time ^c	t _f			140	210	
Source-Drain Diode Ratings and Characteristic (T _C = 25 °C)						
Pulsed Current	I _{SM}				−150	A
Diode Forward Voltage ^a	V _{SD}	I _F = −50 A, V _{GS} = 0 V		−1.2	−1.5	V
Source-Drain Reverse Recovery Time	t _{rr}	I _F = −50 A, di/dt = 100 A/μs		40	80	ns

Notes

- a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%.
b. Guaranteed by design, not subject to production testing.
c. Independent of operating temperature.

**TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)**

TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

THERMAL RATINGS




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